

INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

2SC2837

DESCRIPTION

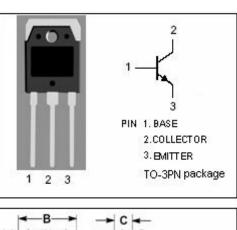
- · High Collector-Emitter Breakdown Voltage-
- : V_{(BR)CEO}=150V(Min)
- Good Linearity of hFE
- Complement to Type 2SA1186
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

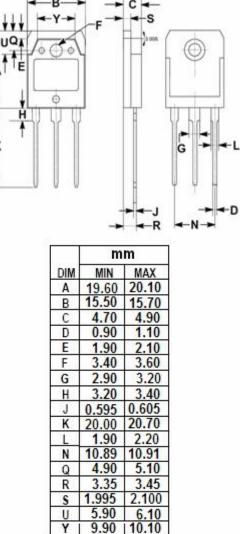
APPLICATIONS

· Designed for audio and general purpose applications

ABSOLUTE MAXIMUM RATINGS(Ta=25C)					
PARAMETER	VALUE	UNIT			
Collector-Base Voltage	150	v			
Collector-Emitter Voltage	150	V			
Emitter-Base Voltage	5	V			
Collector Current-Continuous	10	А			
Base Current-Continuous	2	A			
Collector Power Dissipation @ T _C =25°C	100	W			
Junction Temperature	150	°C			
Storage Temperature Range	-55~150	°C			
	PARAMETER Collector-Base Voltage Collector-Emitter Voltage Emitter-Base Voltage Collector Current-Continuous Base Current-Continuous Collector Power Dissipation @ Tc=25℃ Junction Temperature	PARAMETERVALUECollector-Base Voltage150Collector-Emitter Voltage150Emitter-Base Voltage5Collector Current-Continuous10Base Current-Continuous2Collector Power Dissipation @ Tc=25°C100Junction Temperature150			

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 25mA ; I _B = 0	150			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5.0A; I _B = 0.5A			2.0	V
Ісво	Collector Cutoff Current	V _{CB} = 150V ; I _E = 0			100	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			100	μA
h _{FE}	DC Current Gain	I _C = 3A ; V _{CE} = 4V	50		180	
Сов	Output Capacitance	I _E = 0; V _{CB} = 80V; f _{test} = 1.0MHz		60		pF
fT	Current-Gain—Bandwidth Product	I _E =-1A ; V _{CE} = 12V		70		MHz

Switching times

t _{on}	Turn-on Time		0.2	μs
t _{stg}	Storage Time	$ I_{C} = 5A, R_{L} = 12 \Omega, \\ I_{B1} = -I_{B2} = 0.5A, V_{CC} = 60V $	1.4	μ S
t _f	Fall Time		0.35	μ S

h_{FE} Classifications

0	Р	Y
50-100	70-140	90-180

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